

# Power management (dual digital transistors)

## UMC4N / FMC4A

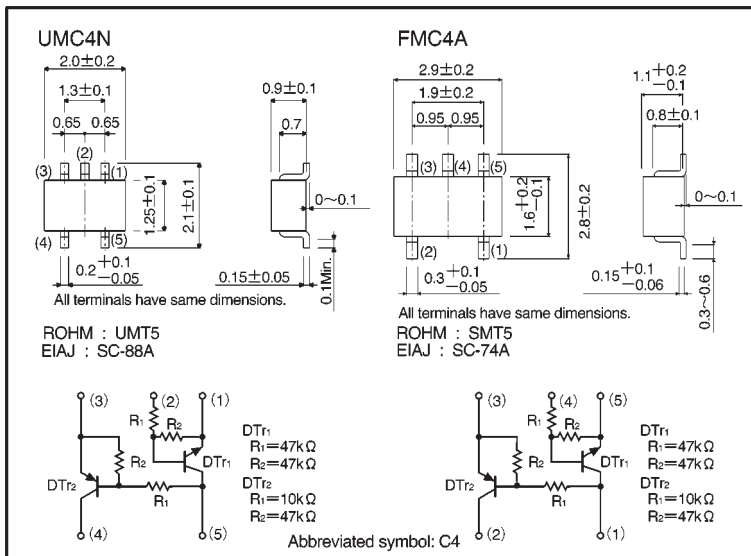
### ●Features

- 1) Both the DTA114Y chip and DTC144E chip in a UMT or SMT package.
- 2) Ideal for power switching circuits.
- 3) Mounting cost and area can be cut in half.

### ●Structure

Epitaxial planar type  
NPN/PNP silicon transistor  
(Built-in resistor type)

### ●External dimensions (Units: mm)



### ●Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ )

Parameter		Symbol	Limits		Unit	
			DT <sub>r1</sub> (NPN)	DT <sub>r2</sub> (PNP)		
Supply voltage		V <sub>CC</sub>	50	−50	V	
Input voltage		V <sub>IN</sub>	40	−40	V	
			−10	6		
Output current		I <sub>o</sub>	30	−100	mA	
		I <sub>C (Max.)</sub>	100	−100		
Power dissipation	UMC4N	P <sub>d</sub>	150 (TOTAL)		mW	*1
	FMC4A		300 (TOTAL)			*2
Junction temperature		T <sub>j</sub>	150		°C	
Storage temperature		T <sub>stg</sub>	−55~+150		°C	

\*1 120mW per element must not be exceeded.

\*2 200mW per element must not be exceeded.

●Electrical characteristics, DTr<sub>1</sub> (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	—	—	0.5	V	V <sub>CC</sub> =5V, I <sub>O</sub> =100 μA
	V <sub>I(on)</sub>	3	—	—	V	V <sub>O</sub> =0.3V, I <sub>O</sub> =2mA
Output voltage	V <sub>O(on)</sub>	—	0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA
Input current	I <sub>I</sub>	—	—	0.18	mA	V <sub>I</sub> =5V
Output current	I <sub>O(off)</sub>	—	—	0.5	μA	V <sub>CC</sub> =50V, V <sub>I</sub> =0V
DC current gain	G <sub>I</sub>	68	—	—	—	V <sub>O</sub> =5V, I <sub>O</sub> =5mA
Transition frequency	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> =10mA, I <sub>E</sub> =-5mA, f=100MHz*
Input resistance	R <sub>I</sub>	32.9	47	61.1	kΩ	—
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2	—	—

\* Transition frequency of the device

●Electrical characteristics, DTr<sub>2</sub> (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	—	—	-0.3	V	V <sub>CC</sub> =-5V, I <sub>O</sub> =-100 μA
	V <sub>I(on)</sub>	-1.4	—	—	V	V <sub>O</sub> =-0.3V, I <sub>O</sub> =-1mA
Output voltage	V <sub>O(on)</sub>	—	-0.1	-0.3	V	I <sub>O</sub> /I <sub>I</sub> =-5mA / -0.25mA
Input current	I <sub>I</sub>	—	—	-0.88	mA	V <sub>I</sub> =-5V
Output current	I <sub>O(off)</sub>	—	—	-0.5	μA	V <sub>CC</sub> =-50V, V <sub>I</sub> =0V
DC current gain	G <sub>I</sub>	68	—	—	—	V <sub>O</sub> =-5V, I <sub>O</sub> =-5mA
Transition frequency	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> =10mA, I <sub>E</sub> =-5mA, f=100MHz*
Input resistance	R <sub>I</sub>	7	10	13	kΩ	—
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	3.7	4.7	5.7	—	—

\*Transition frequency of the device

## ●Packaging specifications

Part No.	Packaging type	Taping	
	Code	TR	T148
	Basic ordering unit (pieces)	3000	3000
UMC4N		○	—
FMC4A		—	○

## ● Electrical characteristic curves

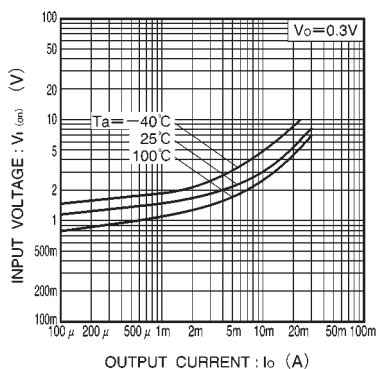
DTr<sub>1</sub>

Fig.1 Input voltage vs. output current (ON characteristics)

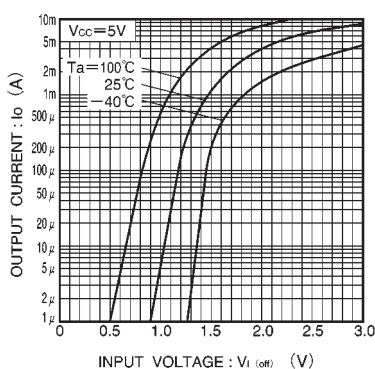


Fig.2 Output current vs. input voltage (OFF characteristics)

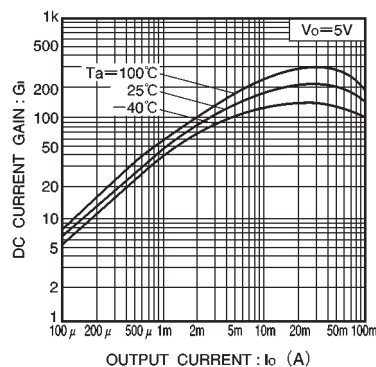


Fig.3 DC current gain vs. output current

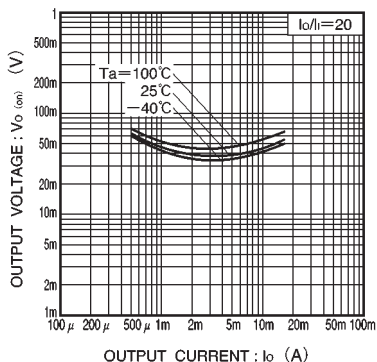
DTr<sub>2</sub>

Fig.4 Output voltage vs. output current

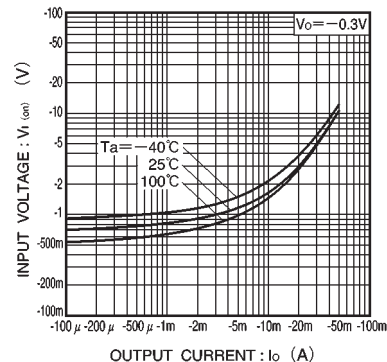


Fig.5 Input voltage vs. output current (ON characteristics)

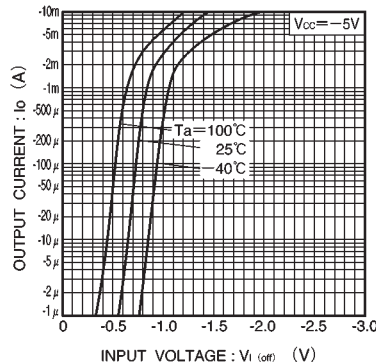


Fig.6 Output current vs. input voltage (OFF characteristics)

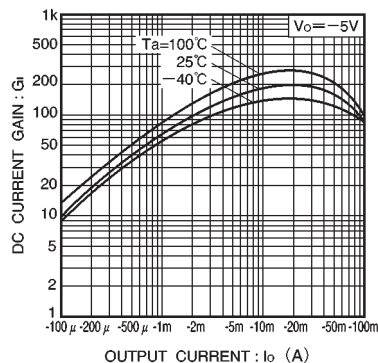


Fig.7 DC current gain vs. output current

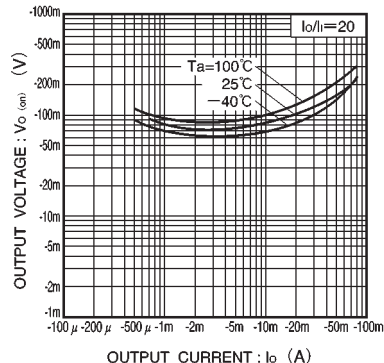


Fig.8 Output voltage vs. output current